

6N135, 6N136, CT4502, CT4503

1Mbit/s High Speed Phototransistor Optocoupler

Features

- High speed 1MBit/s
- High isolation voltage between input and output (Viso=5000 Vrms)
- Guaranteed CTR performance from 0°C to 70°C
- Wide operating temperature range of -55°C to 100°C
- Regulatory Approvals
 - UL UL1577 (E364000)
 - VDE EN60747-5-5(VDE0884-5)
 - CQC GB4943.1, GB8898
 - IEC60065, IEC60950

Applications

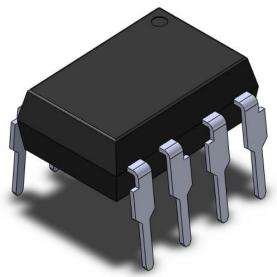
- Line receivers
- Telecommunication equipment
- High speed logic ground isolation
- Feedback loop in switch-mode power supplies
- Home appliances

Description

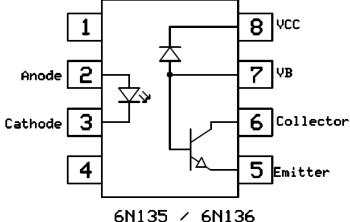
The 6N135, 6N136, CT4502 and CT4503 devices each consist of an infrared emitting diode, optically coupled to a high speed photo detector transistor. A separate connection for the photodiode bias and output-transistor collector increase the speed by several orders of magnitude over conventional phototransistor couplers by reducing the base-collector capacitance of the input transistor.

The devices are packaged in an 8-pin DIP package and also available in gullwing (400mil) and surface mount lead forming.

Package Outline



Schematic



Pin 7 not connected for CT4502/CT4503

Note: Different bending options available. See package

dimension.



Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes	
Viso	Isolation voltage	5000	V _{RMS}	1	
Topr	Operating temperature	-55 ~ +100	°C		
Тѕтс	Storage temperature	-55 ~ +125	°C		
TsoL	Soldering temperature	260	°C	2	
Emitter		•			
l _F	Forward current	25	mA		
I _{FP}	Peak forward current (50% duty, 1ms P.W)	50	mA		
I _{F(TRANS)}	Peak transient current (≤1µs P.W,300pps)	1	А		
V_{R}	Reverse voltage	5	V		
P _D	Power dissipation	40	mW		
Detector	•				
PD	Power dissipation	100	mW		
V _{EBR}	Emitter-Base reverse voltage	5	V		
l _Β	Base current	5	mA		
I _{O(AVG)}	Average Output current	8	mA		
I _{O (Peak)}	Peak Output current	16	mA		
Vo	Output voltage	-0.5 to 20	V		
Vcc	Supply voltage	-0.5 to 30	V		

Notes

- 1. AC for 1 minute, $RH = 40 \sim 60\%$.
- 2. For 10 second peak



Electrical Characteristics

 $T_A = 0$ - 70°C (unless otherwise specified). Typical values are measured at $T_A = 25^{\circ}$ C and $V_{CC} = 5V$

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward voltage	IF = 16mA	-	1.45	1.6	V	
VR	Reverse Voltage	IR = 10μA	5.0	-	-	V	
ΔV _F /ΔT _A	Temperature coefficient of forward voltage	IF =16mA	-	-1.8	-	mV/°C	

Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Мах	Units	Notes
	Logic High Output Current IF	I _F =0mA, V _O =V _{CC} =5.5V,	-	0.001	0.5		
		T _A =25°C					
Іон		I _F =0mA, V _O =V _{CC} =15V,		0.01	1	μA	
		T _A =25°C	-				
		I _F =0mA, V _O =V _{CC} =15V	-	-	50		
loo	Lasia Laur Cumply Cumpet	I _F =16mA, V _O =Open,		140	200	μА	
ICCL	Logic Low Supply Current	Vcc=15V	,				
		I _F =0mA, V _O =Open, V _{CC} =15V,	-	0.01	1		
Іссн	Logic High Supply Current	T _A =25°C				۸	
ICCH		IF=0mA, VO=Open,				- μΑ	
		VCC=15V	-	•	2		



Electrical Characteristics

 $T_A = 0$ - 70°C (unless otherwise specified). Typical values are measured at $T_A = 25^{\circ}$ C and $V_{CC} = 5V$

Transfer Characteristics

Symbol	Parameters		Test Conditions	Min	Тур	Мах	Units	Notes
		6N135		7	-	50		
		6N136	I _F =16mA, V _O =0.4V,V _{CC} =4.5V,					
		CT4502	T _A =25°C	19	-	50		
CTR	Current Transfer	CT4503					%	
CIK	Ratio	6N135		5	-	-	70	
		6N136	L 16m \ \/- 0.5\/ \/- 4.5\/	15	-			
		CT4502	I _F =16mA, V _O =0.5V, V _{CC} =4.5V			-		
		CT4503						
		6N135	I _F =16mA,I _O =1.1mA,V _{CC} =4.5V,		0.18	0.4		
	Vol. Logic Low Output Voltage 6N1 6N1 6N1 6N1 6N1 CT4	CCIVIO	T _A =25°C	-	0.16	0.4		
		6N136	I _F =16mA, I _O =3mA, V _{CC} =4.5V,					
		CT4502	T _A =25°C	-	0.18	0.4		
Voi		CT4503	TA-20 0				V	
VOL		6N135	I _F =16mA, I _O =0.8mA,	_	_	0.5	v	
		011100	V _{CC} =4.5V			0.0		
		6N136	I _F =16mA, I _O =2.4mA,					
		CT4502	V _{CC} =4.5V	-	-	0.5		
		CT4503	VCC-7.5V					



Electrical Characteristics

 $T_A = 0$ - 70°C (unless otherwise specified). Typical values are measured at $T_A = 25^{\circ}$ C and $V_{CC} = 5V$

Switching Characteristics

Symbol	Paramete	ers	Test Conditions	Min	Тур	Max	Units	Notes
	Propagation Delay	6N135	R _L =4.1KΩ, T _{A=} 25°C	-	0.35	1.5		
		611135	R _L =4.1KΩ	-	-	2.0		
T _{PHL}	Time Logic High to Logic Low	6N136	R _L =1.9KΩ, T _A =25°C	-	0.35	0.8	μs	
	Logic Low	CT4502 CT4503	R _L =1.9KΩ	-	-	1.0		
		C14505	R _L =4.1KΩ, T _{A=} 25°C	-	0.5	1.5		
	Propagation Delay	6N135	R _L =4.1KΩ	-	-	2.0		
T _{PLH}	Time Logic Low to	6N136	R _L =1.9KΩ, T _A =25°C	-	0.3	0.8	μs	
	Logic High	CT4502 CT4503	R _L =1.9KΩ	-	-	1.0		
	Common Mode Transient Immunity at Logic High	CNIAGE	I _F = 0mA , V _{CM} =10Vp-p,	4.000				
		6N135 R _L =4.1KΩ, T _A =25°C	1,000	-	-			
СМн		6N136	I _F = 0mA , V _{CM} =10Vp-p,	1,000		-	V/µs	
CIVIH		CT4502	R _L =1.9KΩ, T _A =25°C		-			
	at Logic Fligh	CT4503	I _F = 0mA , V _{CM} =1500Vp-p,	15,000	20,000			
		014303	R _L =1.9KΩ, T _A =25°C	13,000	20,000	,		
		6N135	I _F = 16mA , V _{CM} =10Vp-p,	1 000				
	Common Mode Transient Immunity		1,000	_	-			
CML		6N136	I _F = 16mA , V _{CM} =10Vp-p,	1,000			V/µs	
CIVIL	at Logic Low	CT4502 R _L =1.9KΩ, T _A =25°C	1,000	-	-	ν/μο		
	at Logic Low	IF = 16mA , V _{CM} =1500Vp	I _F = 16mA , V _{CM} =1500Vp-p,	15,000	20,000			
		014000	R _L =1.9KΩ, T _A =25°C					



CTR, Normalized Collector Current

1.0

8.0

0.6

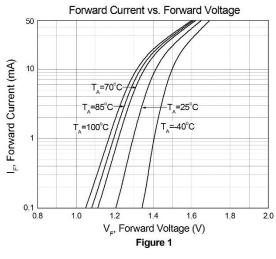
0.4

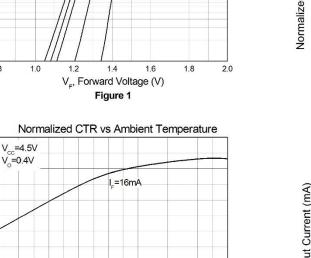
0.2

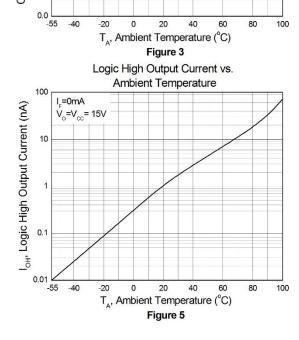
-40

6N135, 6N136, CT4502, CT4503 1Mbit/s High Speed Phototransistor Optocoupler

Typical Characteristic Curves



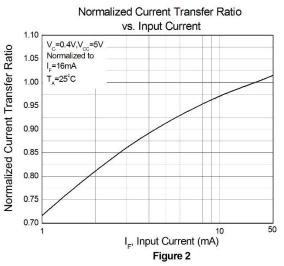


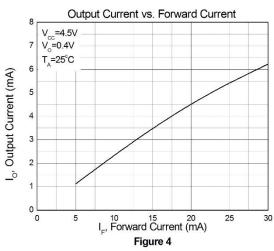


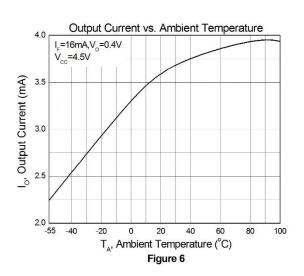
20

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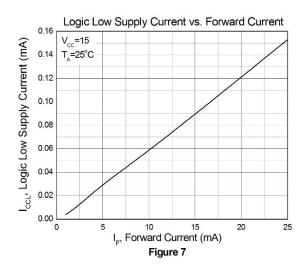
80

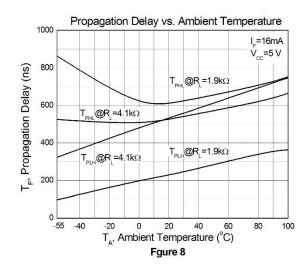


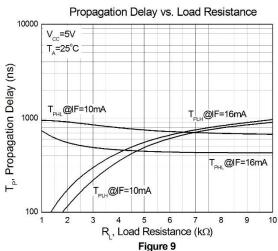






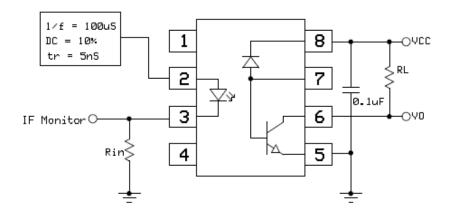


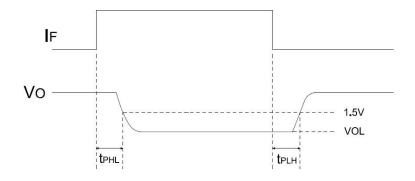






Test Circuits

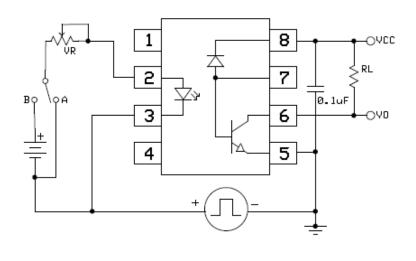


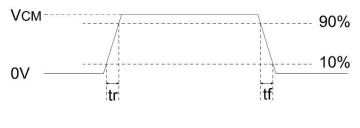


Switching Time Test Circuit



Test Circuits







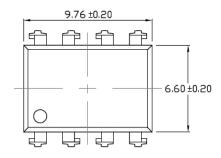


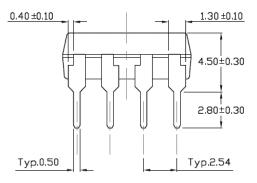
CMR Test Circuit

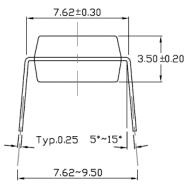


Package Dimension Dimensions in mm unless otherwise stated

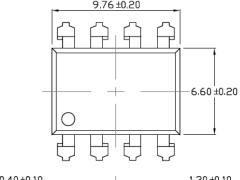
Standard DIP - Through Hole

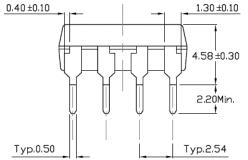


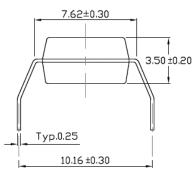




Gullwing (400mil) Lead Forming – Through Hole (M Type)

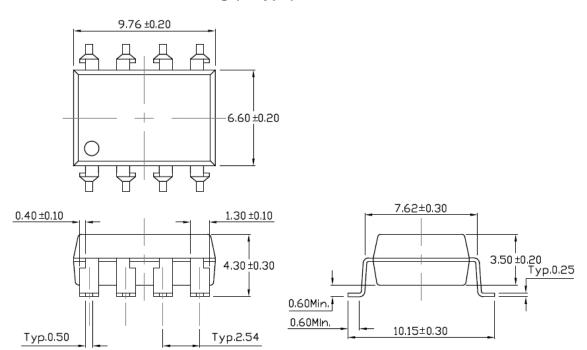




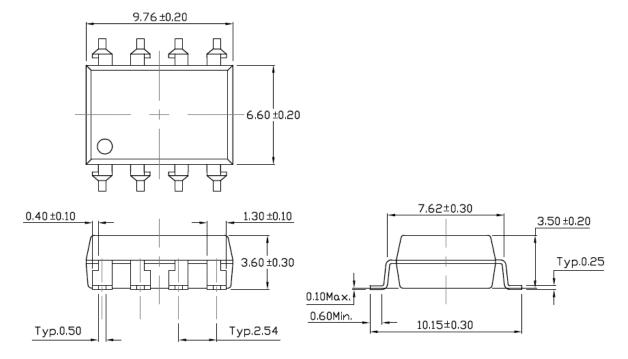




Surface Mount Lead Forming (S Type)

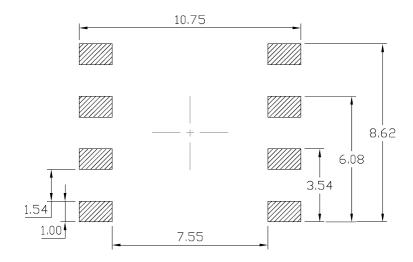


Surface Mount (Low Profile) Lead Forming (SL Type)

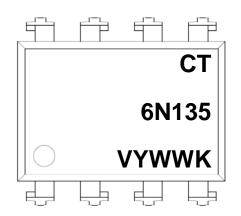


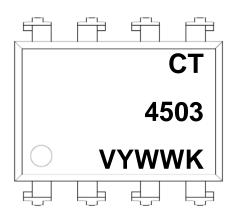


Recommended Solder Mask Dimensions in mm unless otherwise stated



Device Marking





CT : Denotes "CT Micro" 6N135 : Product Number

4503 : Product Number

V : VDE Option
Y : Fiscal Year
WW : Work Week

K : Production Code



Ordering Information

6N13X(V)(Y)(Z) or CT450X(V)(Y)(Z)

X = Part No. (5,6 for 6N13X series), (2,3 for CT450X series)

V = VDE Option (V or None)

Y = Lead form option (S, SL, M or none)

Z = Tape and reel option (T1, T2 or none)

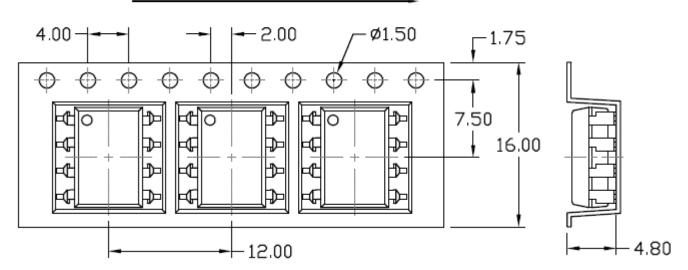
Option	Option Description	
None	None Standard 8 Pin Dip	
М	M Gullwing (400mil) Lead Forming	
S(T1)	Surface Mount Lead Forming – With Option 1 Taping	1000 Units/Reel
S(T2)	S(T2) Surface Mount Lead Forming – With Option 2 Taping	
SL(T1)	SL(T1) Surface Mount (Low Profile) Lead Forming– With Option 1 Taping	
SL(T2)	1000 Units/Reel	



Carrier Tape Specifications Dimensions in mm unless otherwise stated

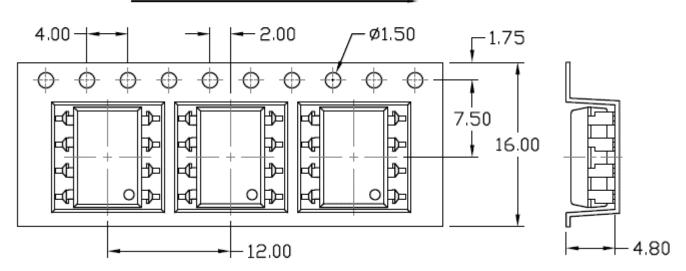
Option S(T1) & SL(T1)

Input Direction



Option S(T2) & SL(T2)

Input Direction





Wave soldering (follow the JEDEC standard JESD22-A111)

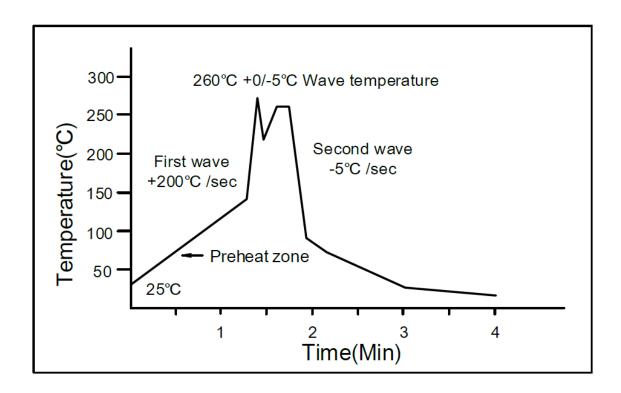
One time soldering is recommended within the condition of temperature.

Temperature: 260+0/-5°C.

Time: 10 sec.

Preheat temperature:25 to 140°C.

Preheat time: 30 to 80 sec.



Iron soldering (follow the standard MIL-STD 202G, Method 210F)

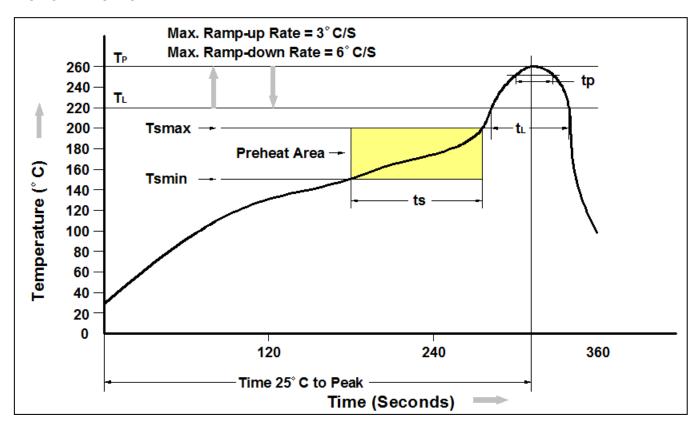
Allow single lead soldering in every single process.

One time soldering is recommended. Temperature: 350+±10°C

Time: 5 sec max.



Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t∟ to t⊳)	3°C/second max.
Liquidous Temperature (T _L)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



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